NSN 5961-01-033-2330

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View Online at https://aerobasegroup.com/nsn/5961-01-033-2330 **Inclosure Material:** Ceramic **Overall Length:** 0.280 inches **Overall Width:** 0.300 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter **Current Rating Per Characteristic:** 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 40.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unc **Terminal Type And Quantity:** 4 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli Fiig: A110a0